Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-037-8677

View Online at https://aerobasegroup.com/nsn/5961-01-037-8677
Inclosure Material:
Glass and metal
Overall Length:
Between 0.230 inches and 0.300 inches
Terminal Length:
1.000 inches
Overall Diameter:
Between 0.085 inches and 0.105 inches
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case and gold plated leads
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
15.0 reverse voltage, dc and 15.0 reverse breakdown voltage, dc
Current Rating Per Characteristic:
50.00 milliamperes source cutoff current preset and 100.00 milliamperes forward current, average peak
Power Rating Per Characteristic:
250.0 milliwatts small-signal input power, common-collector absolute
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius ambient air
Precious Material And Location:
Terminal surface gold
Precious Material:
Gold
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0